

DONGGUAN ZHONGGUI ELECTRONICS CO., LTD

Digital Transistors (Built-in Resistors)

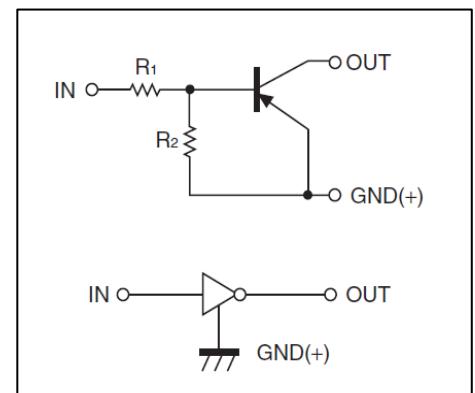
DTA143EM/DTA143EE/DTA143EUA DTA143EKA /DTA143ECA/DTA143ESA

DIGITAL TRANSISTOR (PNP)

FEATURES

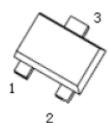
- Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit)
- The bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input. They also have the advantage of almost completely eliminating parasitic effects
- Only the on/off conditions need to be set for operation, making device design easy

• Equivalent Circuit



PIN CONNECTIONS and MARKING

DTA143EM

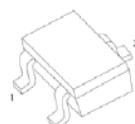


MARKING:13

SOT-723

1. IN
2. GND
3. OUT

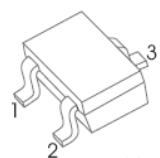
DTA143EE



SOT-523

1. IN
2. GND
3. OUT

DTA143EUA

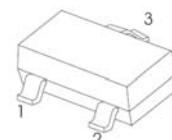


MARKING:13

SOT-323

1. IN
2. GND
3. OUT

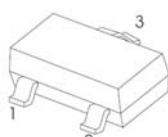
DTA143EKA



SOT-23-3L

1. IN
2. GND
3. OUT

DTA143ECA



MARKING:13

SOT-23

1. IN
2. GND
3. OUT

DTA143ESA



TO-92S

1. GND
2. OUT
3. IN

MAXIMUM RATINGS(Ta=25°C unless otherwise noted)

Symbol	Parameter	Limits(DTA143E□)						Unit
		M	E	UA	KA	CA	SA	
V _{CC}	Supply Voltage			-50				V
V _{IN}	Input Voltage			-30~+10				V
I _O	Output Current			-100				mA
P _D	Power Dissipation	100	150	200	200	200	300	mW
T _j	Junction Temperature			150				°C
T _{stg}	Storage Temperature			-55~+150				°C

ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Input voltage	V _{I(off)}	V _{CC} =-5V,I _O =-100μA	-0.5			V
	V _{I(on)}	V _O =-0.3V,I _O =-20 mA			-3	V
Output voltage	V _{O(on)}	I _O /I _I =-10mA/-0.5mA			-0.3	V
Input current	I _I	V _I =-5V			-1.8	mA
Output current	I _{O(off)}	V _{CC} =-50V,V _I =0			-0.5	μA
DC current gain	G _I	V _O =-5V,I _O =-10mA	30			
Input resistance	R _I		3.29	4.7	6.11	kΩ
Resistance ratio	R ₂ /R ₁		0.8	1	1.2	
Transition frequency	f _T	V _O =-10V,I _O =-5mA,f=100MHz		250		MHz

Typical Characteristics

DTA143EXX

